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FAIRCHILD SEMICONDUCTOR®

October 2013

FCH47N60F_F085

N-Channel MOSFET

600V, 47A, 75mΩ

Features

- Typ $r_{DS(on)}$ = 66mΩ at V_{GS} = 10V, I_D = 47A
- Typ $Q_{g(tot)}$ = 190nC at V_{GS} = 10V, I_D = 47A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Description

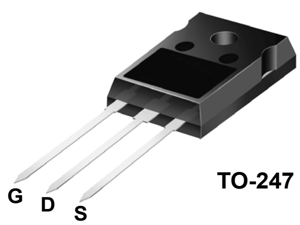
SuperFET™ is Fairchild's proprietary new generation of high voltage MOSFETs utilizing an advanced charge balance mechanism for outstanding low on-resistance and lower gate charge performance.

This advanced technology has been tailored to minimize conduction loss, provide superior switching performance, and withstand extreme dv/dt rate and higher avalanche energy.

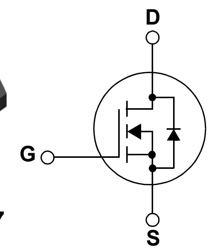
Consequently, SuperFET is suitable for various automotive DC/DC power conversion.

Applications

- Automotive On Board Charger
- Automotive DC/DC converter for HEV



TO-247



For current package drawing, please refer to the Fairchild website at www.fairchildsemi.com/packaging

100% RoHS COMPLIANT

MOSFET Maximum Ratings T_J = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{DSS}	Drain to Source Voltage	600	V
V_{GS}	Gate to Source Voltage	±30	V
I_D	Drain Current - Continuous (V_{GS}=10) (Note 1) T_C = 25°C	47	A
	Pulsed Drain Current T_C = 25°C	See Figure4	
E_{AS}	Single Pulse Avalanche Energy (Note 2)	810	mJ
P_D	Power Dissipation	417	W
	Derate above 25°C	3.3	W/°C
T_J, T_{STG}	Operating and Storage Temperature	-55 to + 150	°C
$R_{\theta JC}$	Thermal Resistance Junction to Case	0.3	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance Junction to Ambient (Note 3)	50	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FCH47N60F	FCH47N60F_F085	TO-247	-	-	30 units

Notes:
1: Current is limited by bondwire configuration.
2: Starting T_J = 25°C, L = 5mH, I_{AS} = 18A, V_{DD} = 100V during inductor charging and V_{DD} = 0V during time in avalanche
3: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in^2 pad of 2oz copper.

Electrical Characteristics T_J = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions		Min	Typ	Max	Units
Off Characteristics							
B_{VDSS}	Drain to Source Breakdown Voltage	I_D = 250μA, V_{GS} = 0V		600	-	-	V
I_{DSS}	Drain to Source Leakage Current	V_{DS}=600V, V_{GS} = 0V	T_J = 25°C	-	-	10	μA
			T_J = 150°C(Note 4)	-	-	1	mA
I_{GSS}	Gate to Source Leakage Current	V_{GS} = ±30V		-	-	±100	nA
On Characteristics							
$V_{GS(th)}$	Gate to Source Threshold Voltage	V_{GS} = V_{DS}, I_D = 250μA		3.0	4.0	5.0	V
$r_{DS(on)}$	Drain to Source On Resistance	I_D = 47A, V_{GS}= 10V	T_J = 25°C	-	66	75	mΩ
			T_J = 150°C(Note 4)	-	180	223	mΩ
Dynamic Characteristics							
C_{iss}	Input Capacitance	V_{DS} = 25V, V_{GS} = 0V, f = 1MHz		-	5900	8000	pF
C_{oss}	Output Capacitance			-	3200	4200	pF
C_{rss}	Reverse Transfer Capacitance			-	250	-	pF
R_g	Gate Resistance	f = 1MHz		-	1	-	Ω
$Q_{g(ToT)}$	Total Gate Charge at 10V	V_{GS} = 0 to 10V	V_{DD} = 300V, I_D = 47A	-	190	250	nC
$Q_{g(th)}$	Threshold Gate Charge	V_{GS} = 0 to 2V		-	12	18	nC
Q_{gs}	Gate to Source Gate Charge			-	40	-	nC
Q_{gd}	Gate to Drain “Miller“ Charge			-	96	-	nC

Switching Characteristics

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
t_{on}	Turn-On Time	V_{DD} = 300V, I_D = 47A, V_{GS} = 10V, R_G = 25Ω	-	-	410	ns
$t_{d(on)}$	Turn-On Delay Time		-	110	-	ns
t_r	Rise Time		-	160	-	ns
$t_{d(off)}$	Turn-Off Delay Time		-	540	-	ns
t_f	Fall Time		-	125	-	ns
t_{off}	Turn-Off Time		-	-	1000	ns
Drain-Source Diode Characteristics						
V_{SD}	Source to Drain Diode Voltage	I_{SD} = 47A, V_{GS} = 0V	-	-	1.4	V
		I_{SD} = 23.5A, V_{GS} = 0V	-	-	1.25	V
T_{rr}	Reverse Recovery Time	I_F = 47A, dI_{SD}/dt = 100A/μs, V_{DD}=480V	-	207	350	ns
Q_{rr}	Reverse Recovery Charge		-	2.0	3.6	uC

Notes:

4: The maximum value is specified by design at T_J = 150°C. Product is not tested to this condition in production.

Typical Characteristics

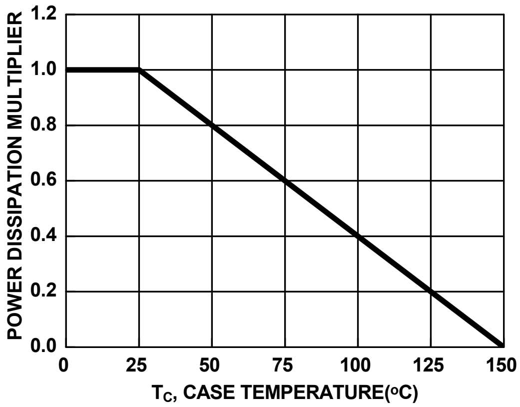


Figure 1. Normalized Power Dissipation vs Case Temperature

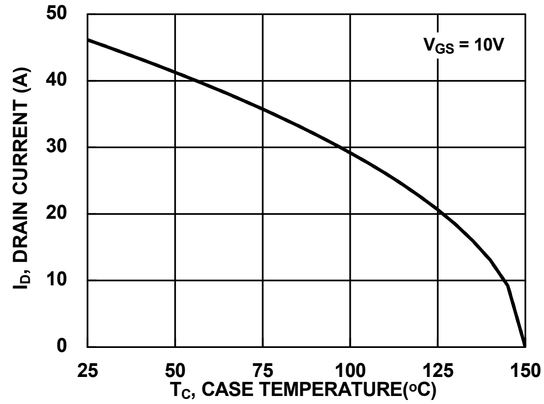


Figure 2. Maximum Continuous Drain Current vs Case Temperature

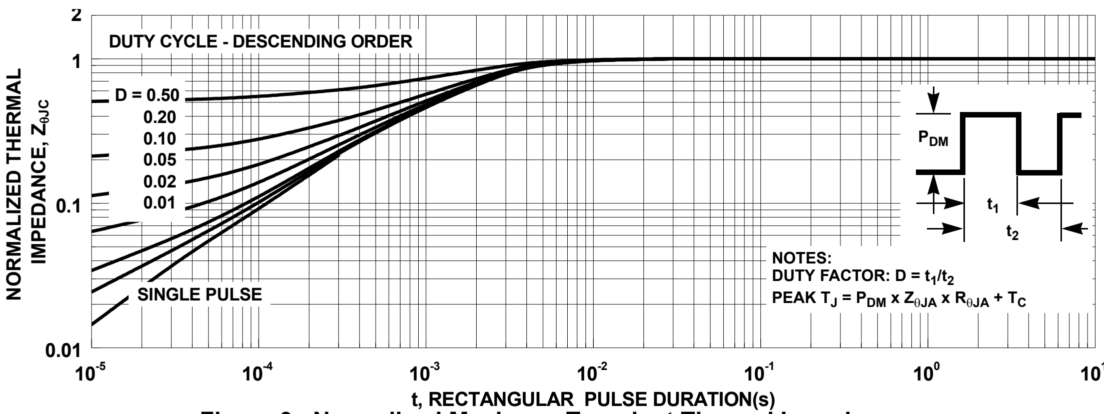


Figure 3. Normalized Maximum Transient Thermal Impedance

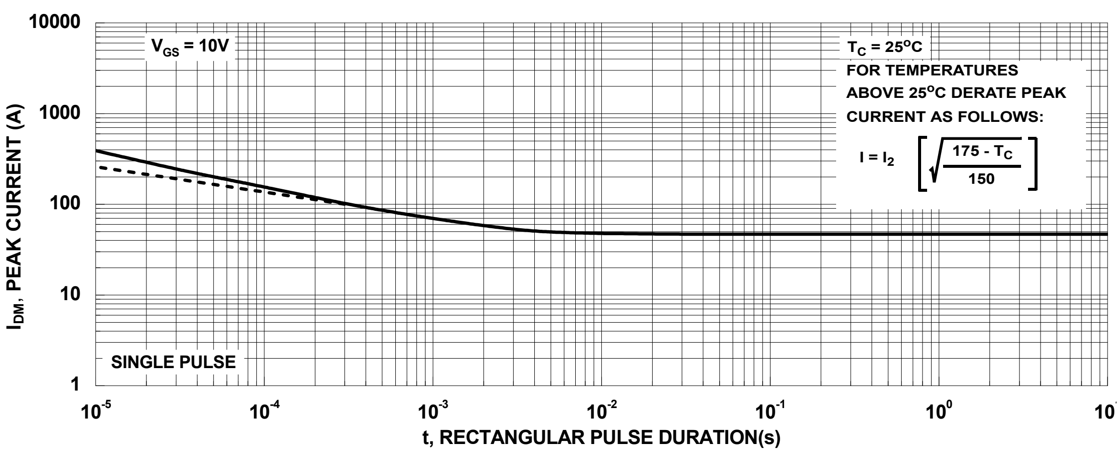


Figure 4. Peak Current Capability

Typical Characteristics

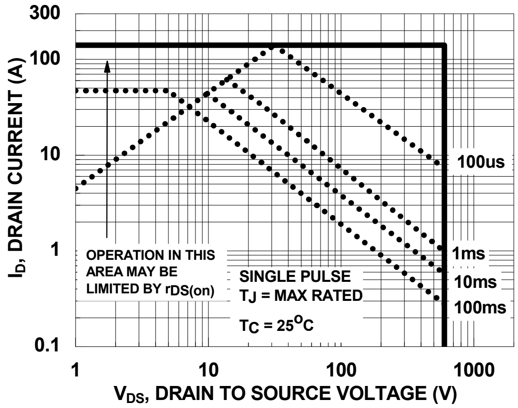


Figure 5. Forward Bias Safe Operating Area

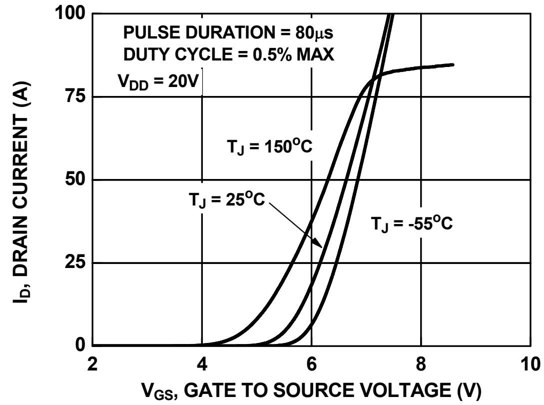


Figure 6. Transfer Characteristics

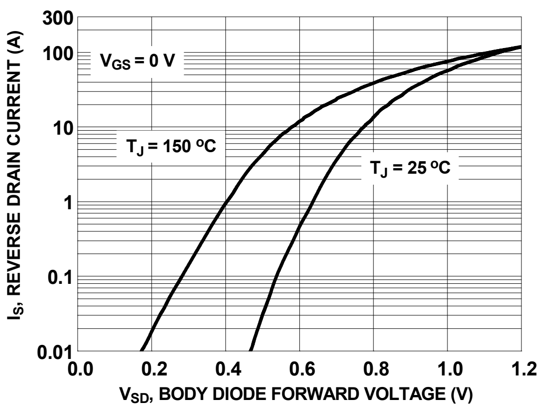


Figure 7. Forward Diode Characteristics

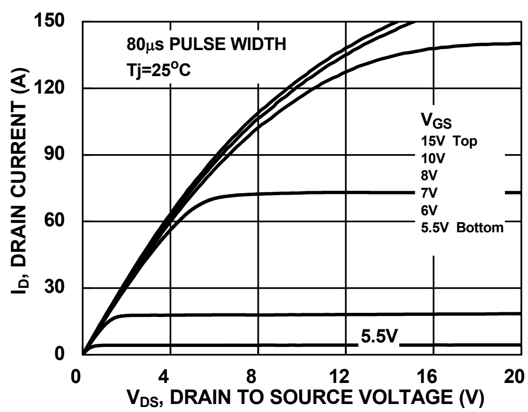


Figure 8. Saturation Characteristics

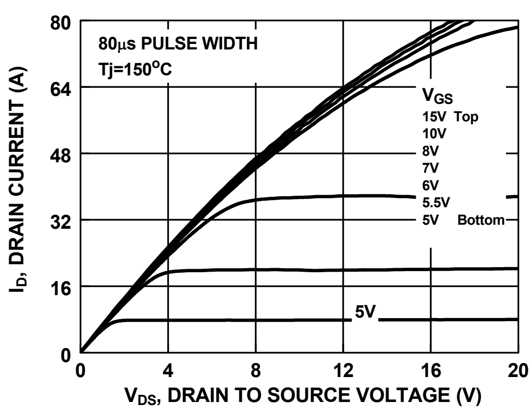


Figure 9. Saturation Characteristics

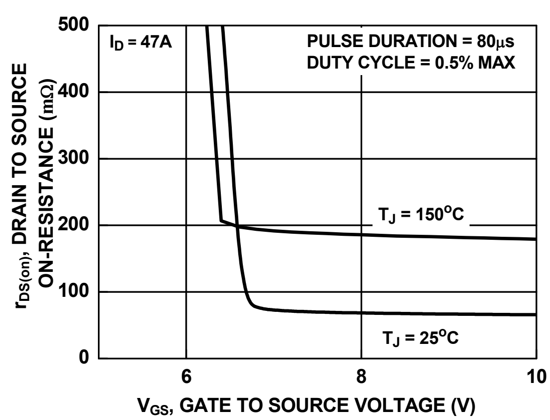


Figure 10. Rdson vs Gate Voltage

Typical Characteristics

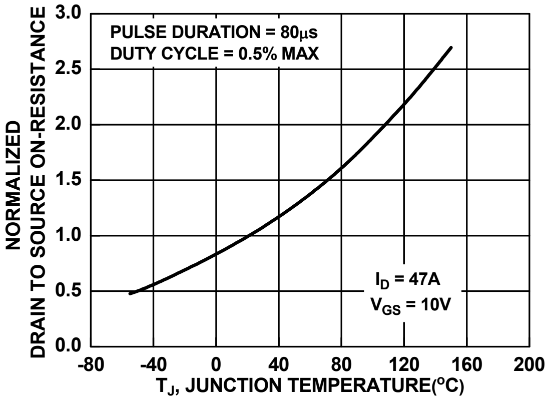


Figure 11. Normalized Rdson vs Junction Temperature

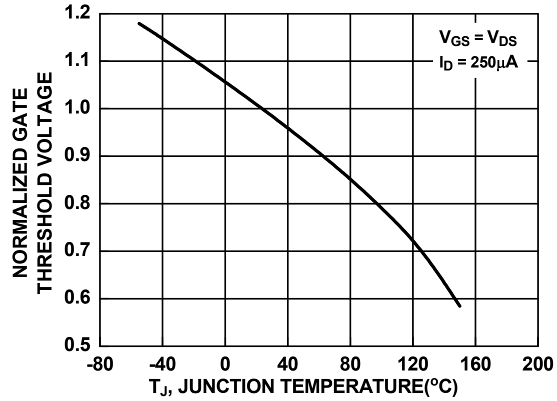


Figure 12. Normalized Gate Threshold Voltage vs Temperature

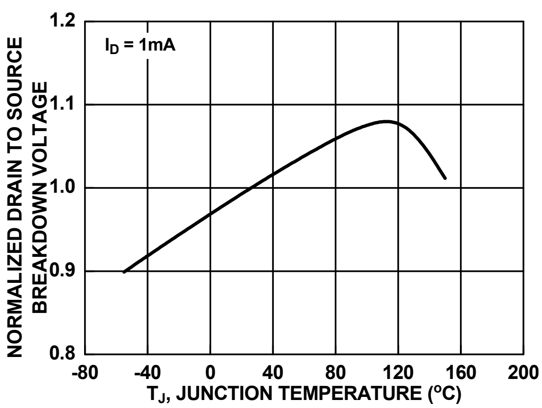


Figure 13. Normalized Drain to Source Breakdown Voltage vs Junction Temperature

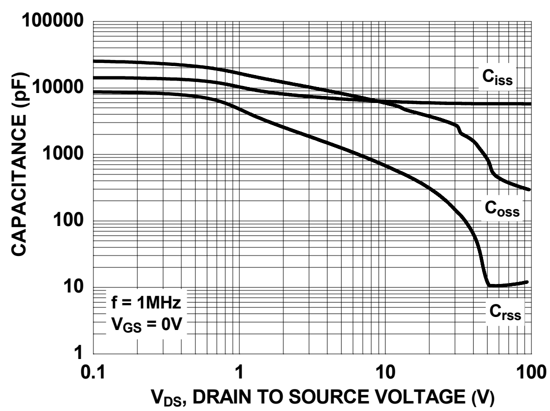


Figure 14. Capacitance vs Drain to Source Voltage

Figure 16.

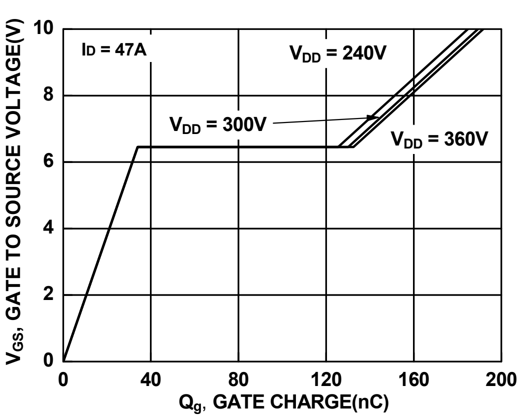


Figure 15. Gate Charge vs Gate to Source Voltage

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Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Rev. I66

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